


APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention	PARTIALLY DEPLETED SOI MOSFET DEVICE		
Application Type : regular, utility Attorney Docket Number : NAUP0549USA			
Correspondence address: Customer Number: 027765			
			
Inventors Information: <u>Inventor 1:</u> Applicant Authority Type: Inventor Citizenship: TW Given Name: Shiao-Shien Family Name: Chen Residence: City of Residence: Hsin-Chu City Country of Residence: TW Address-1 of Mailing Address: 3F-19, No.27, Sh-Pin Rd. Address-2 of Mailing Address: City of Mailing Address: Hsin-Chu City State of Mailing Address: Postal Code of Mailing Address: Country of Mailing Address: TW Phone: Fax: E-mail: <u>Inventor 2:</u> Applicant Authority Type: Inventor Citizenship: TW Given Name: Lu-Shiang Family Name: Huang Residence: City of Residence: Hsin-Chu City			

Country of Residence: TW
Address-1 of Mailing Address: No. 590, Sec. 1, Kuang-Fu Rd.
Address-2 of Mailing Address:
City of Mailing Address: Hsin-Chu City
State of Mailing Address:
Postal Code of Mailing Address:
Country of Mailing Address: TW
Phone:
Fax:
E-mail:

Inventor 3:

Applicant Authority Type: Inventor
Citizenship: TW
Given Name: Tien-Hao
Family Name: Tang
Residence:
City of Residence: Taipei Hsien
Country of Residence: TW
Address-1 of Mailing Address: No. 3-1, Alley 4, Lane 106, Pao-Chien Rd.,
Address-2 of Mailing Address: Chung-Ho City
City of Mailing Address: Taipei Hsien
State of Mailing Address:
Postal Code of Mailing Address:
Country of Mailing Address: TW
Phone:
Fax:
E-mail:

Attorney Information:

practitioner(s) at Customer Number:
027765



as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.